# 4V Drive Nch MOS FET RSS070N05

## Structure

Silicon N-channel MOS FET

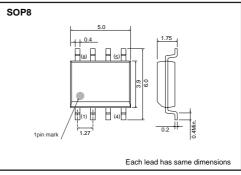
# Features

- 1) Built-in G-S Protection Diode.
- 2) Small Surface Mount Package (SOP8).

### Applications

Power switching , DC / DC converter , Inverter

# •External dimensions (Unit : mm)



### Packaging dimensions

	Package	Taping		
Туре	Code	ТВ		
	Basic ordering unit (pieces)	2500		
RSS070N0	0			

## ●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit	
Drain-source voltage		V <sub>DSS</sub>	45	V
Gate-source voltage	V <sub>GSS</sub>	20	V	
Drain current	Continuous	Ι <sub>D</sub>	±7.0	А
Drain current	Pulsed	$I_{DP}$ *1	±28	А
Source current Continuous		I <sub>S</sub>	1.6	А
(Body diode)	Pulsed	$I_{SP}$ *1	28	А
Total power dissipation	$P_D$ *2	2	W	
Chanel temperature	$T_{ch}$	150	°C	
Range of Storage temperature		T <sub>stg</sub>	-55 to +150	°C

\*1 PW≤10μs, Duty cycle≤1%

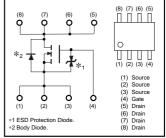
\*2 Mounted on a ceramic board

# Thermal resistance

Parameter	Symbol	Limits	Unit
Chanel to ambient	R <sub>th(ch-a)</sub> *	62.5	°C/W
* Maximtad an a sevence beaud			

\* Mounted on a ceramic board

### •Equivalent circuit



 A protection diode is included between the gate and the source terminals to protect the diode against static electricity when the product is in use.Use a protection circuit when the fixed voltage are exceeded.

# ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	lgss	-	-	10	μΑ	Vgs=20V, Vds=0V
Drain-source breakdown voltage	V(BR) DSS	45	_	-	V	ID= 1mA, VGS=0V
Zero gate voltage drain current	IDSS	-	_	1	μΑ	V <sub>DS</sub> = 45V, V <sub>GS</sub> =0V
Gate threshold voltage	VGS (th)	1.0	-	2.5	V	V <sub>DS</sub> = 10V, I <sub>D</sub> = 1mA
Static drain-source on-state resistance		-	18	25	mΩ	I <sub>D</sub> =7A, V <sub>GS</sub> = 10V
	$R_{DS(on)^*}$	-	23	32	mΩ	I <sub>D</sub> = 7A, V <sub>GS</sub> = 4.5V
		_	25	35	mΩ	I <sub>D</sub> = 7A, V <sub>GS</sub> = 4.0V
Forward transfer admittance	Y <sub>fs</sub> *	6.0	-	_	S	V <sub>DS</sub> = 10V, I <sub>D</sub> = 7A
Input capacitance	Ciss	-	1000	_	pF	V <sub>DS</sub> = 10V
Output capacitance	Coss	-	230	_	pF	V <sub>GS</sub> =0V
Reverse transfer capacitance	Crss	-	125	_	pF	f=1MHz
Turn-on delay time	${ m t}$ d (on) $^{*}$	-	16	_	ns	Vdd≒ 25V
Rise time	tr *	-	27	-	ns	$I_{D}=3.5A$
Turn-off delay time	td (off) *	-	57	-	ns	Vgs= 10V R∟=7.1Ω
Fall time	t <sub>f</sub> *	-	21	-	ns	R <sub>G</sub> =10Ω
Total gate charge	Qg *	-	12.0	16.8	nC	V <sub>DD</sub> ≒25V V <sub>GS</sub> =5V
Gate-source charge	Q <sub>gs</sub> *	-	3.0	-	nC	I <sub>D</sub> =7A
Gate-drain charge	Q <sub>gd</sub> *	-	4.6	_	nC	R∟=3.6Ω R₀=10Ω

\*Pulsed

# •Body diode characteristics (Source-Drain) (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Forward voltage	V <sub>SD</sub> *	-	_	1.2	V	I <sub>S</sub> =1.6A/V <sub>GS</sub> =0V

\* pulsed

### 10 V<sub>DS</sub>=10V Ised Static Drain-Source On-State Drain Current : I<sub>b</sub> [A] 1 75°C 25 0.1 0.01 2.0 2.5 3.0 3.5 1.0 1.5 Gate-Source Voltage : V<sub>GS</sub> [V]

Fig.1 Typical Transfer Characteristics

Electrical characteristic curves

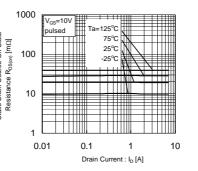
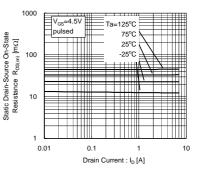


Fig.2 Static Drain-Source On-State Resistance vs. Drain Current (1)



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Fig.3 Static Drain-Source On-State Resistance vs. Drain Current (2)

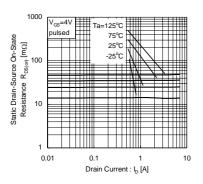


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current (3)

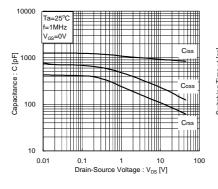


Fig.7 Typical capacitance vs. Source-Drain Voltage

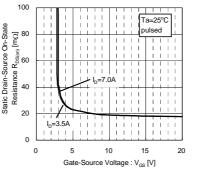


Fig.5 Static Drain-Source On-State Resistance vs. Gate-Source Voltage

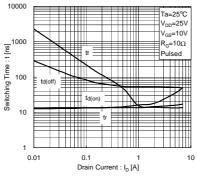


Fig.8 Switching Characteristics

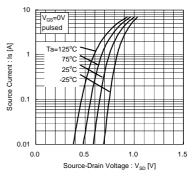
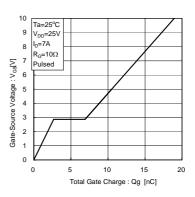


Fig.6 Source-Current vs. Source-Drain Voltage





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# Measurement circuits

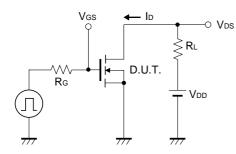


Fig.10 Switching Time Test Circuit

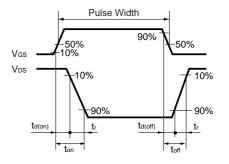


Fig.11 Switching Time Waveforms

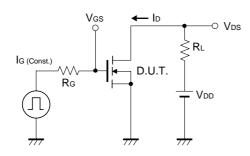
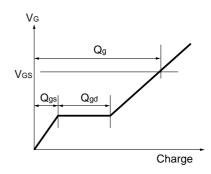
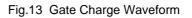


Fig.12 Gate Charge Test Circuit





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